



CPH3114

Bipolar Transistor -15V, -1.5A, Low VCE(sat), PNP Single CPH3

ON Semiconductor®

<http://onsemi.com>

Applications

- Relay drivers, lamp drivers, motor drivers, flash

Features

- Adoption of MBIT processes
- Large current capacity
- Low collector-to-emitter saturation voltage
- High-speed switching
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm)
- High allowable power dissipation

Specifications

Absolute Maximum Ratings at Ta=25°C

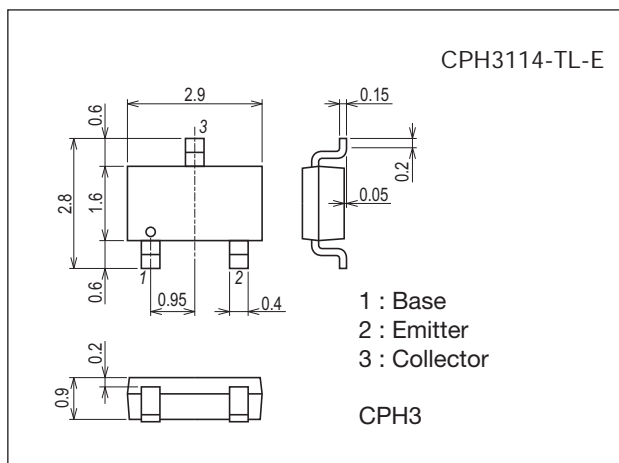
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		-15	V
Collector-to-Emitter Voltage	V _{CEO}		-15	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	I _C		-1.5	A
Collector Current (Pulse)	I _{CP}		-3	A
Base Current	I _B		-300	mA
Collector Dissipation	P _C	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

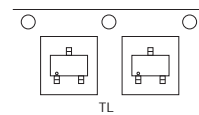
7015A-003



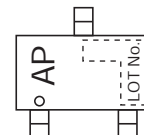
Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

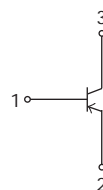
Packing Type: TL



Marking



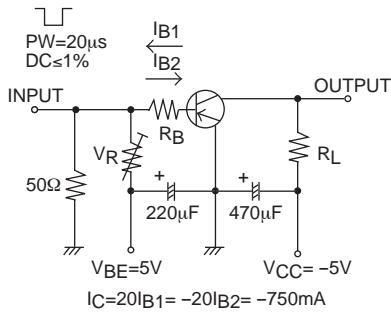
Electrical Connection



Electrical Characteristics at Ta=25°C

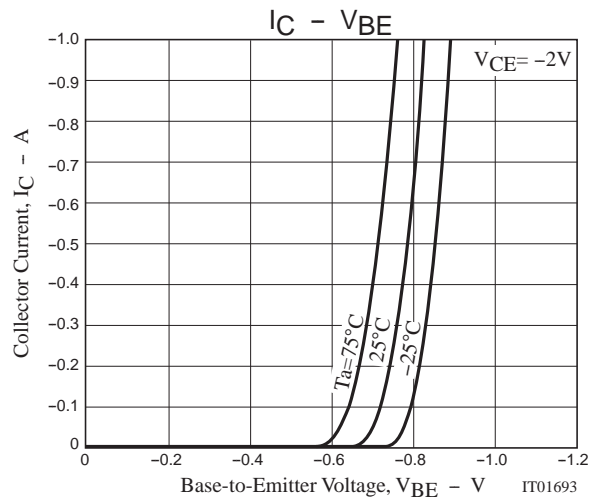
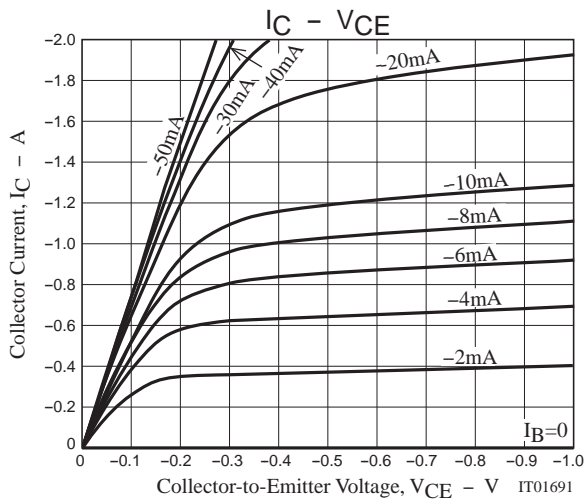
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = -12V, I_E = 0A$			-0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -4V, I_C = 0A$			-0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = -2V, I_C = -100mA$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE} = -2V, I_C = -300mA$		350		MHz
Output Capacitance	C_{ob}	$V_{CB} = -10V, f = 1MHz$		17		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C = -750mA, I_B = -15mA$		-120	-180	mV
	$V_{CE(sat)2}$	$I_C = -1.5mA, I_B = -30mA$		-210	-320	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -750mA, I_B = -15mA$		-0.85	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0A$	-15			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-15			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu A, I_C = 0A$	-5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		50		ns
Storage Time	t_{stg}			90		ns
Fall Time	t_f			15		ns

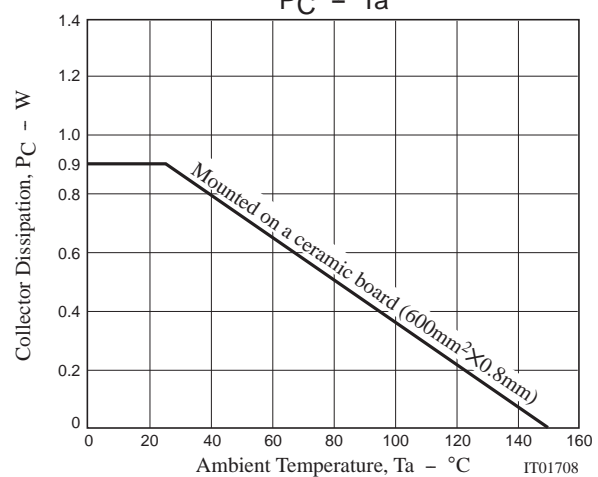
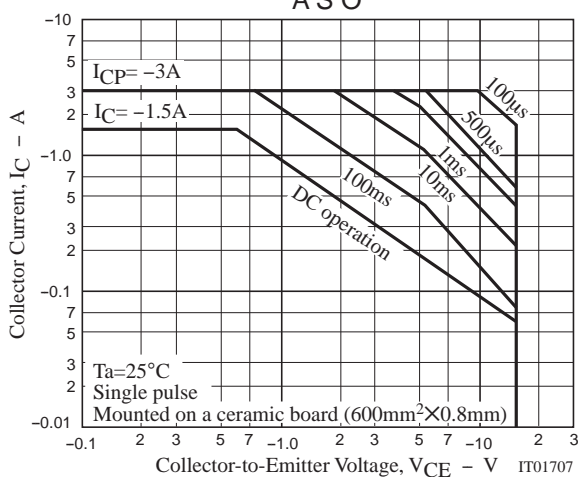
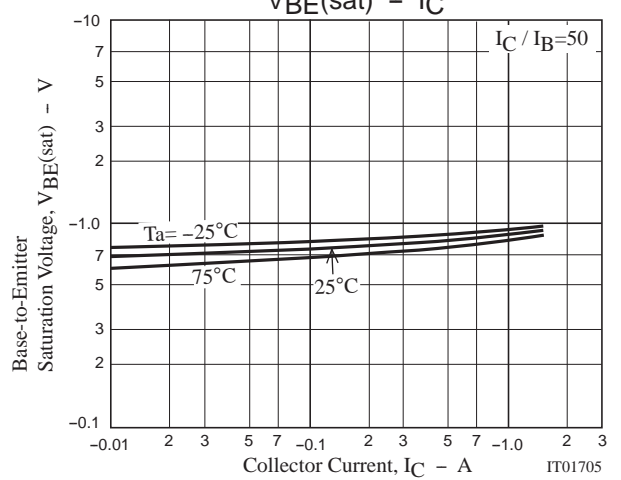
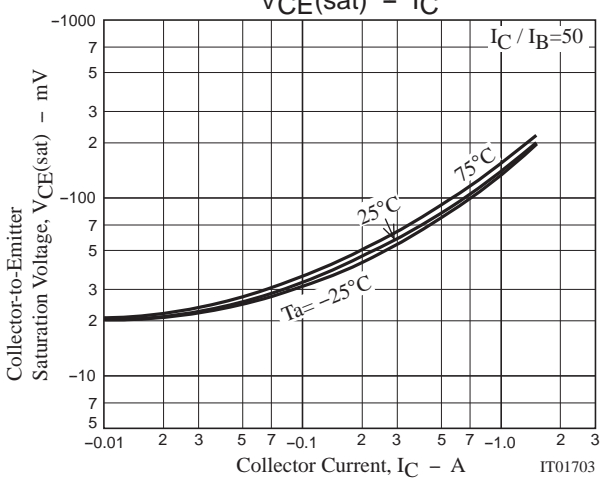
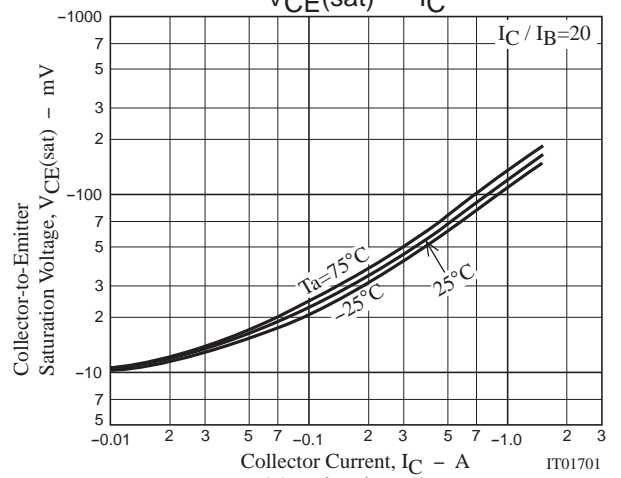
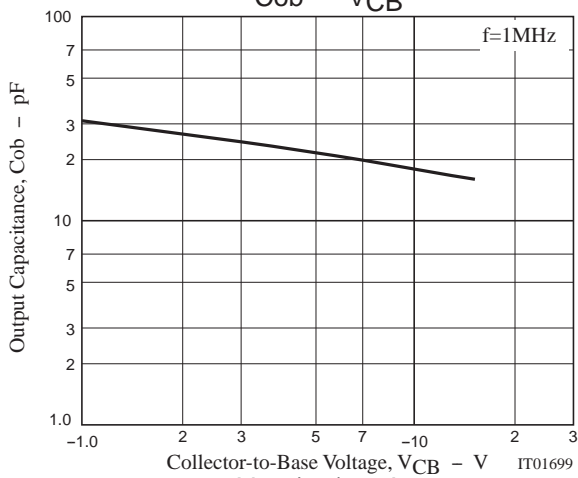
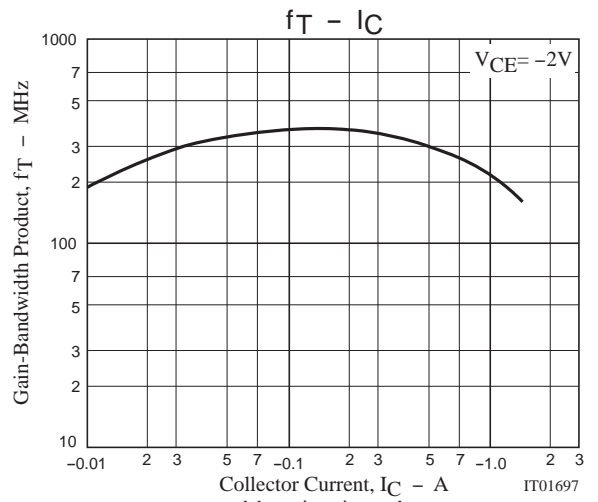
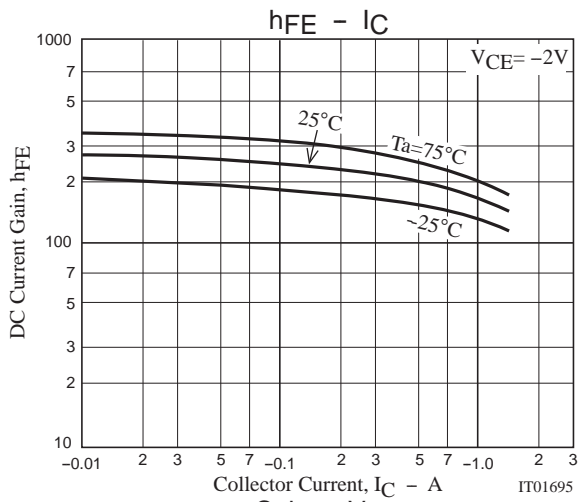
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
CPH3114-TL-E	CPH3	3,000pcs./reel	Pb Free





Embossed Taping Specification

CPH3114-TL-E

1. Packing Format

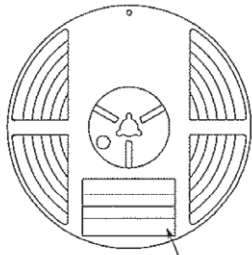
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

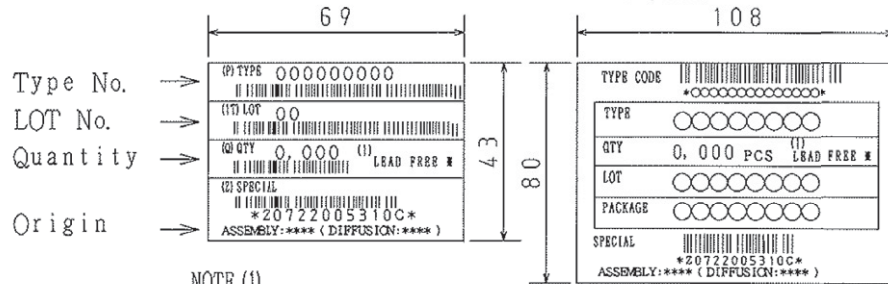
Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label



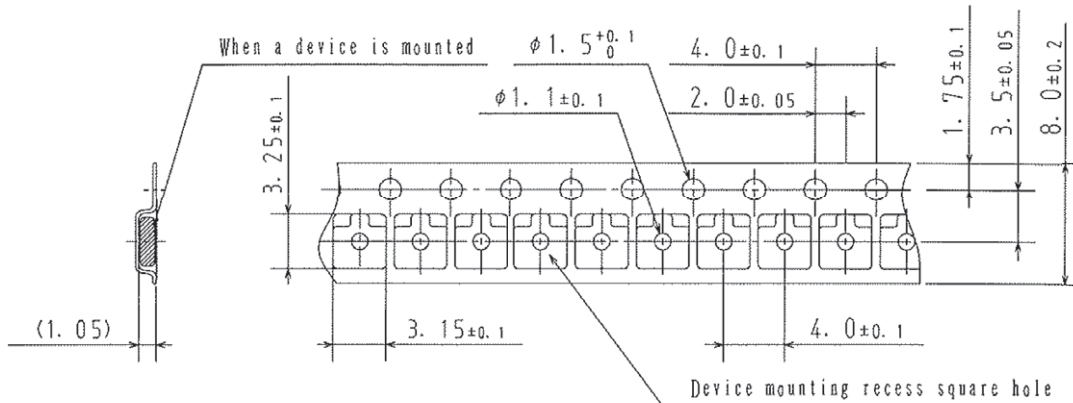
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

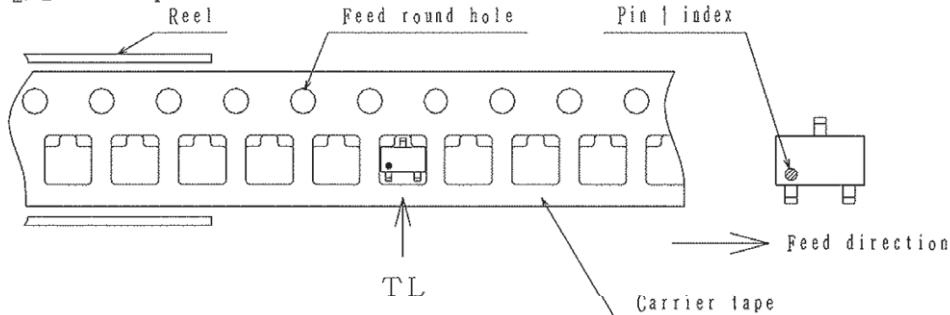
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

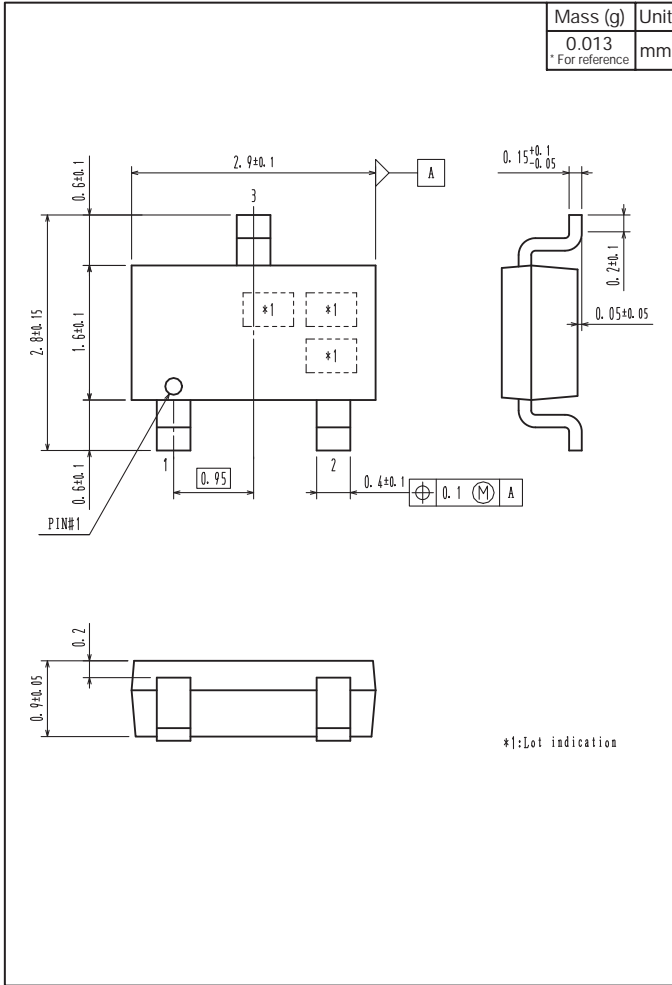


Those with one electrode terminal on the feed hole side.....TL

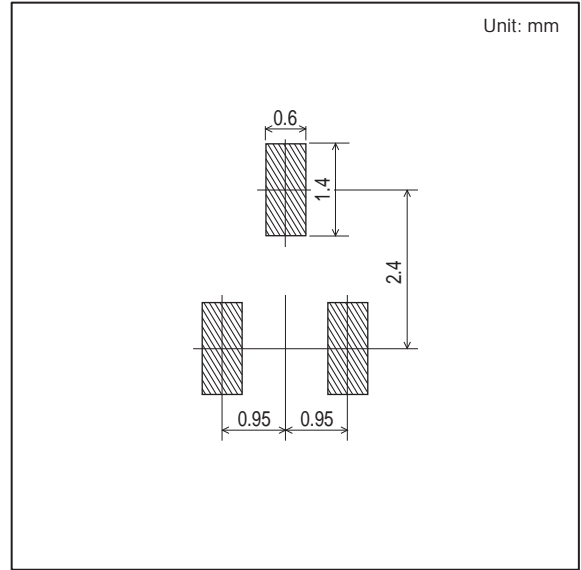
CPH3114

Outline Drawing

CPH3114-TL-E



Land Pattern Example



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